



US007021984B2

(12) **United States Patent**
Park et al.

(10) **Patent No.:** **US 7,021,984 B2**
(45) **Date of Patent:** **Apr. 4, 2006**

(54) **ORGANIC ELECTROLUMINESCENT
DISPLAY DEVICE AND METHOD OF
FABRICATING THE SAME**

(75) Inventors: **Jaе-Yong Park**, Gyeonggi-do (KR);
Ock-Hee Kim, Gyeonggi-do (KR);
Choong-Keun Yoo, Incheon (KR);
Nam-Yang Lee, Gyeonggi-do (KR);
Kwan-Soo Kim, Gyeonggi-do (KR)

(73) Assignee: **LG. Philips LCD Co., Ltd.**, Seoul
(KR)

(*) Notice: Subject to any disclaimer, the term of this
patent is extended or adjusted under 35
U.S.C. 154(b) by 0 days.

(21) Appl. No.: **10/885,119**

(22) Filed: **Jul. 7, 2004**

(65) **Prior Publication Data**

US 2004/0242117 A1 Dec. 2, 2004

Related U.S. Application Data

(62) Division of application No. 10/329,485, filed on Dec.
27, 2002, now Pat. No. 6,922,015.

(30) **Foreign Application Priority Data**

Apr. 25, 2002 (KR) 2002-22813

(51) **Int. Cl.**

H05B 33/10 (2006.01)

H01J 9/26 (2006.01)

(52) **U.S. Cl.** **445/25; 445/24**

(58) **Field of Classification Search** **445/24,**
445/25

See application file for complete search history.

(56) **References Cited**

U.S. PATENT DOCUMENTS

5,929,474 A	7/1999	Huang et al.	
5,984,748 A *	11/1999	Ritter et al.	445/24
6,175,345 B1	1/2001	Kuribayashi et al.	
6,198,220 B1	3/2001	Jones et al.	
6,548,961 B1	4/2003	Barth et al.	
6,608,449 B1	8/2003	Fukunaga	
2002/0158577 A1	10/2002	Shimoda et al.	
2003/0127972 A1	7/2003	Han et al.	

FOREIGN PATENT DOCUMENTS

JP	11185954 A *	7/1999
JP	2001-177509	4/2001
KR	2002-0047889	6/2002
KR	2004-0079476	9/2004
WO	WO-02/078101	10/2002

* cited by examiner

Primary Examiner—Mariceli Santiago

(74) *Attorney, Agent, or Firm*—Morgan Lewis & Bockius
LLP

(57) **ABSTRACT**

An organic electroluminescent display device includes a first substrate, a second substrate spaced apart from and facing the first substrate to form a space therebetween, an array element on an inner surface of the first substrate, an organic electroluminescent diode on an inner surface of the second substrate, a seal pattern along a peripheral portion between the first and second substrates, and a connection pattern electrically interconnecting the array element and the organic electroluminescent diode, wherein a pressure within the space between the first and second substrates is lower than an ambient atmospheric pressure.

9 Claims, 8 Drawing Sheets

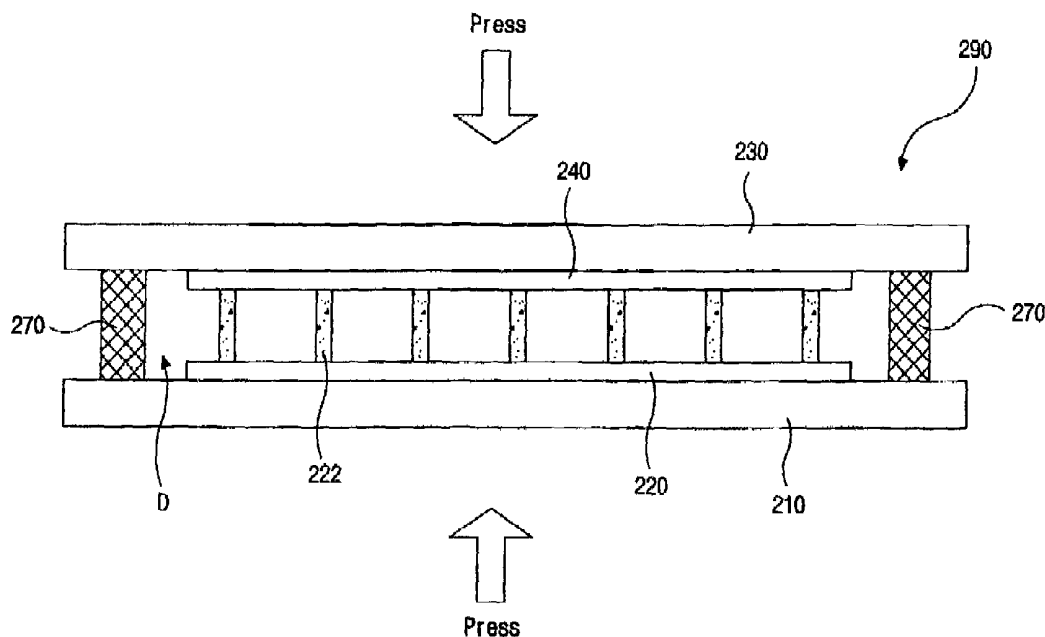


FIG. 1

RELATED ART

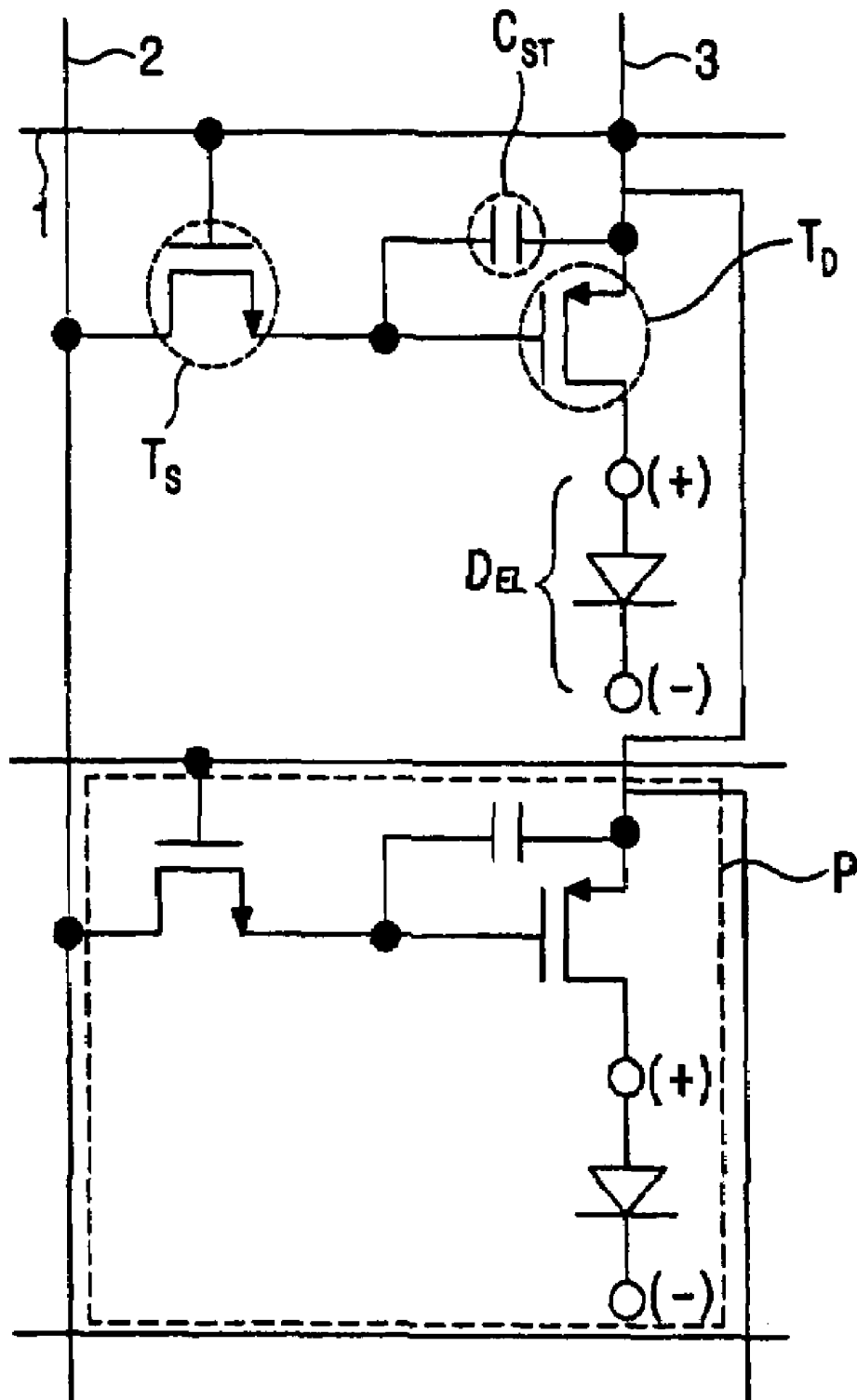


FIG. 2
RELATED ART

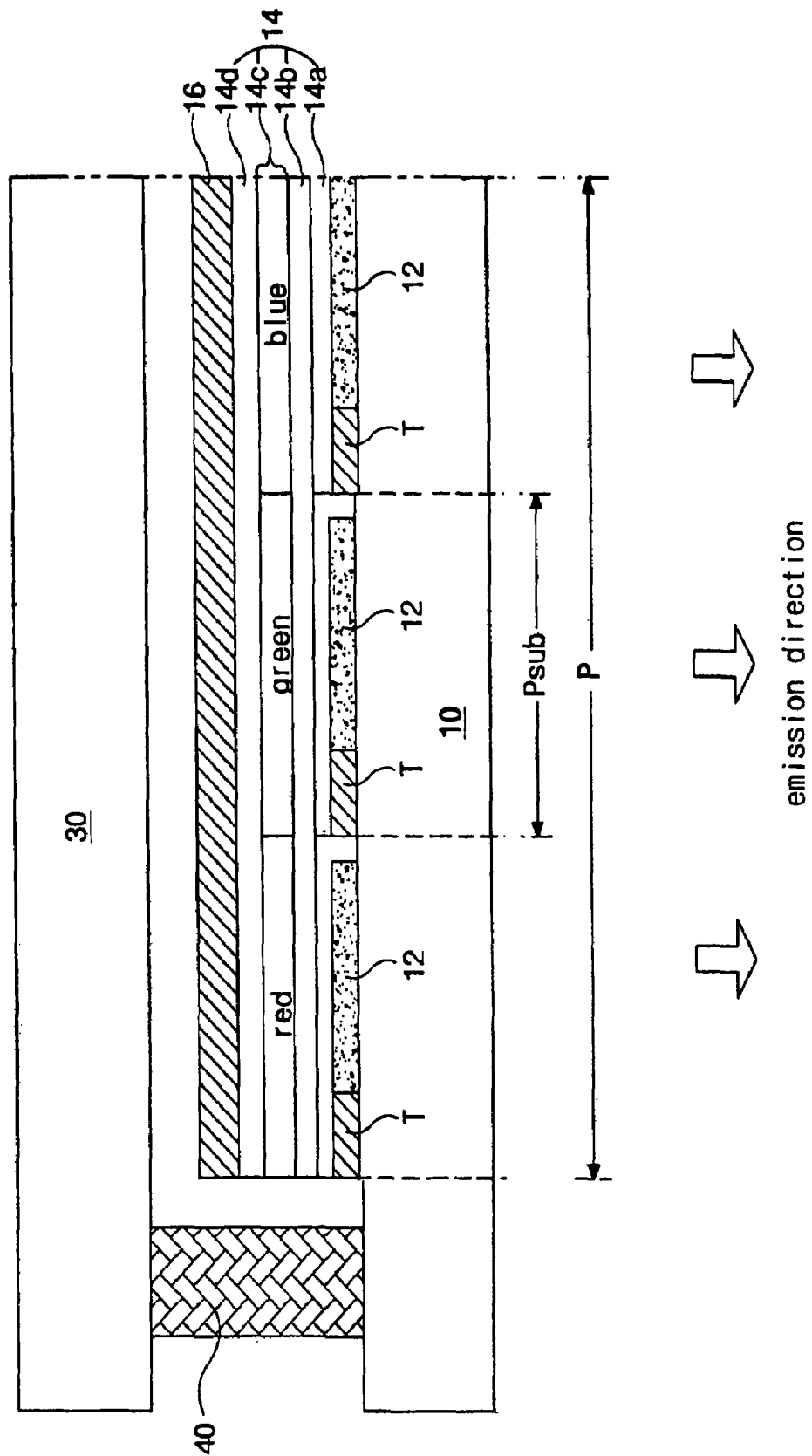


FIG. 3
RELATED ART

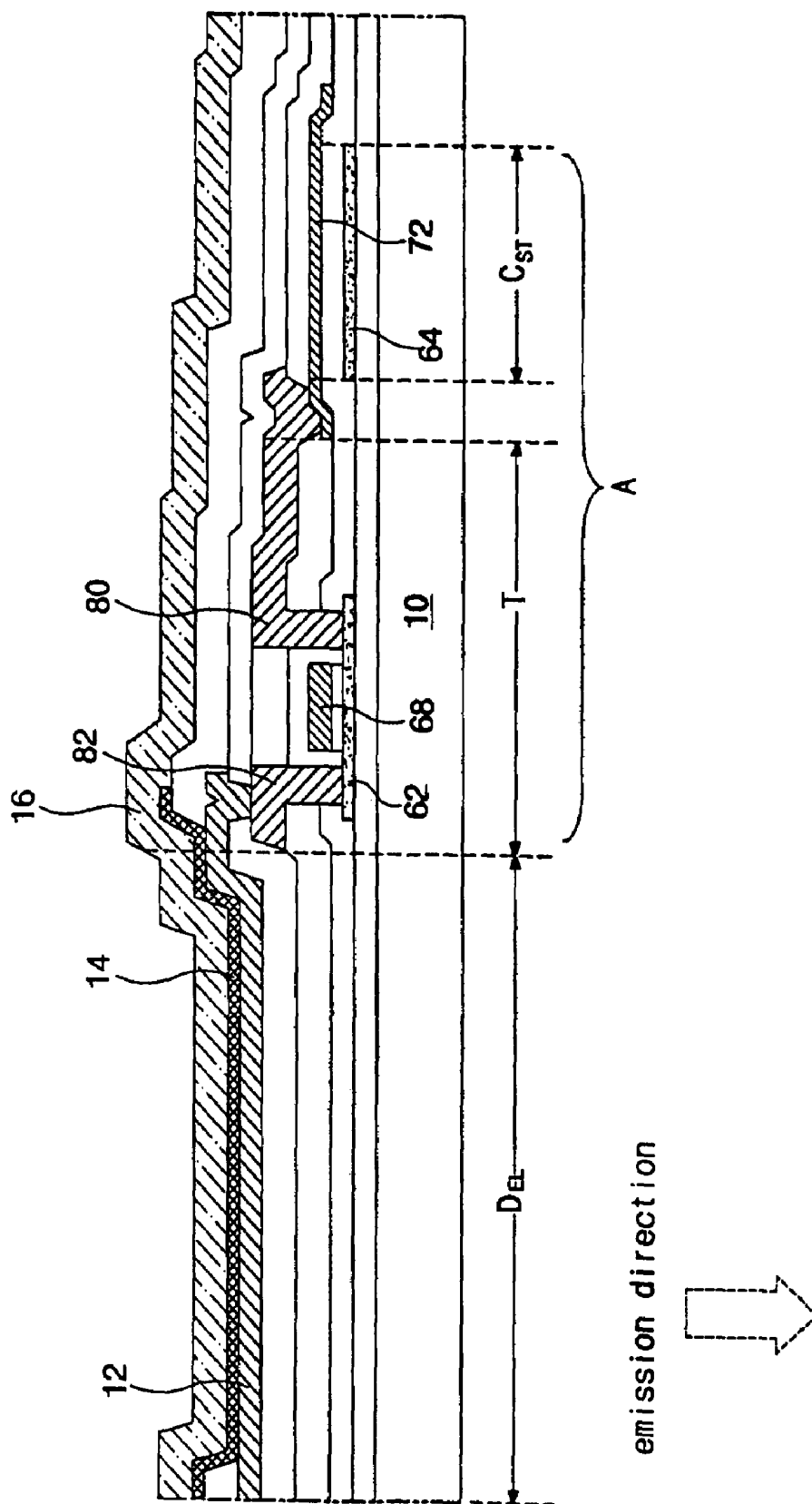


FIG. 4

RELATED ART

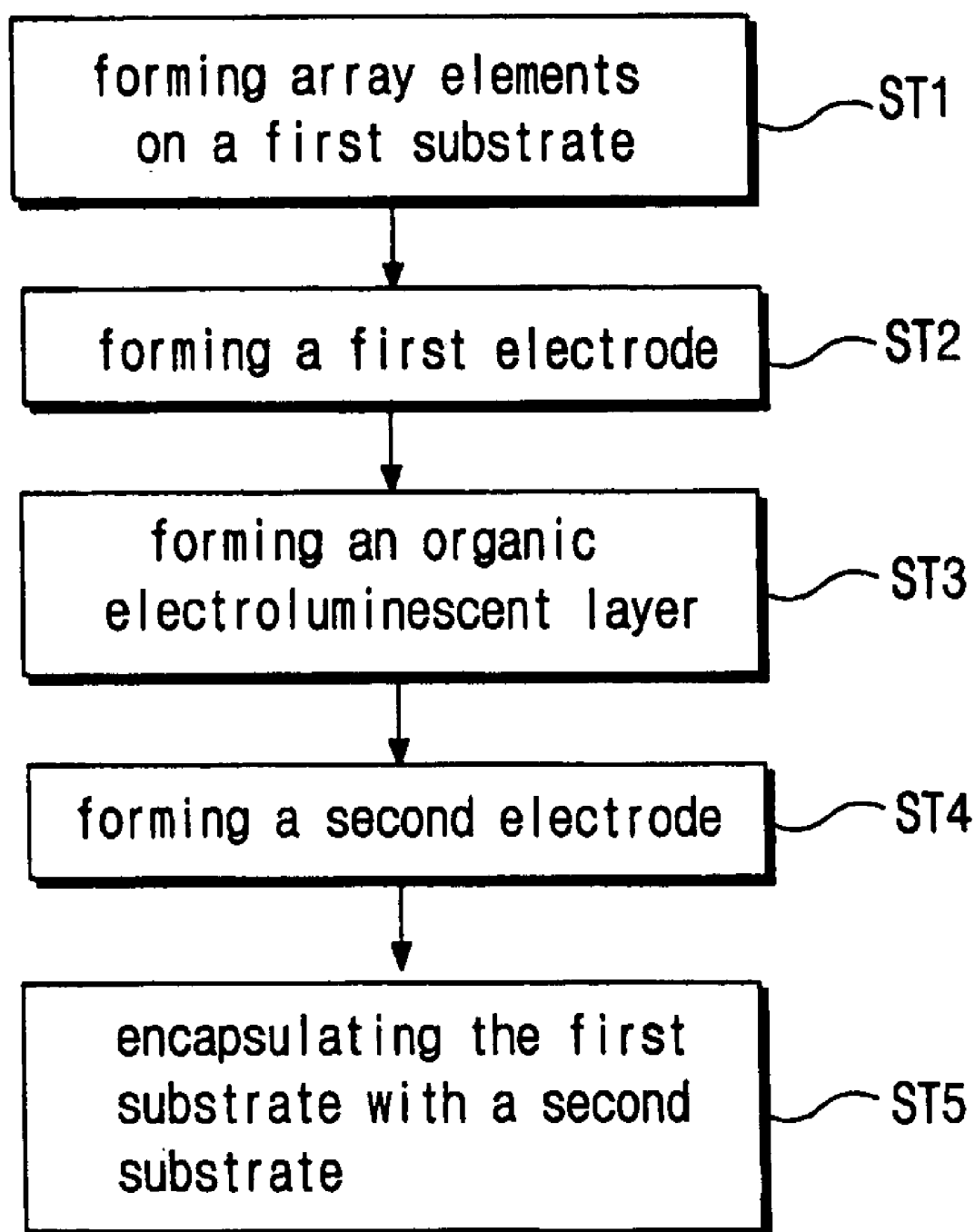


FIG. 5

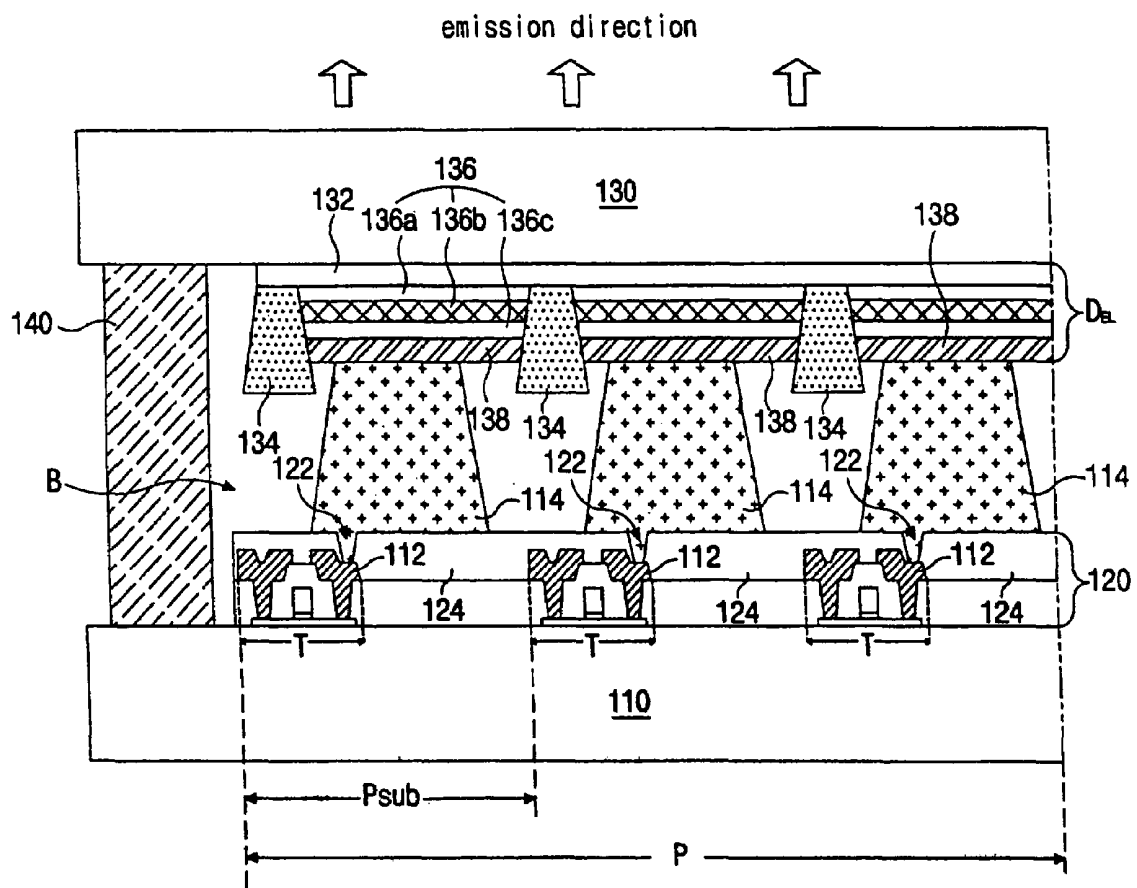


FIG. 6

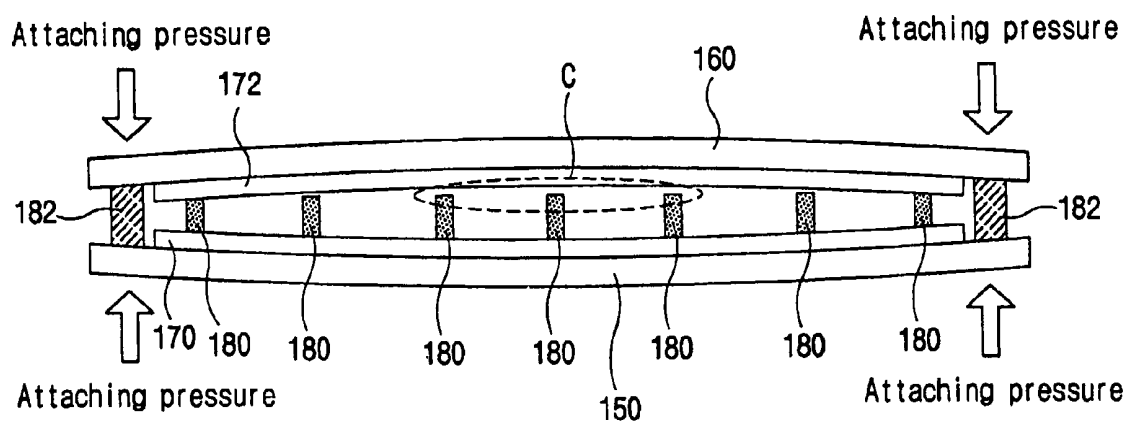


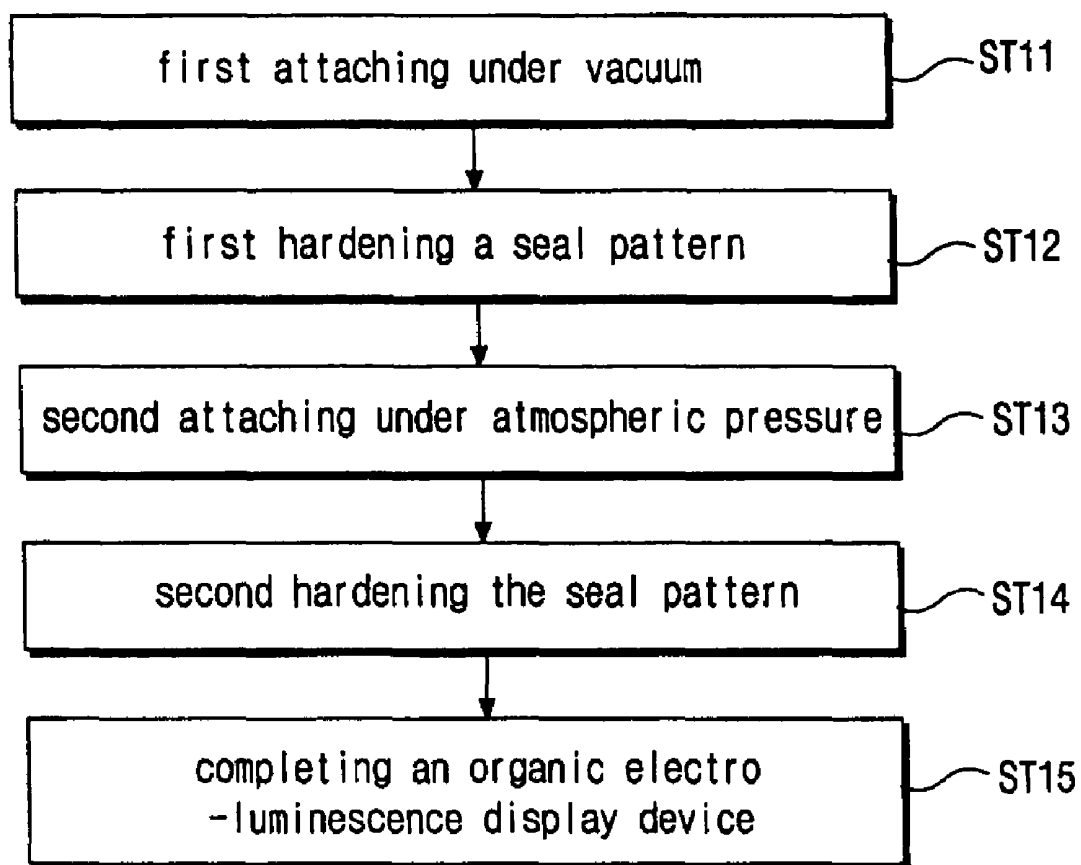
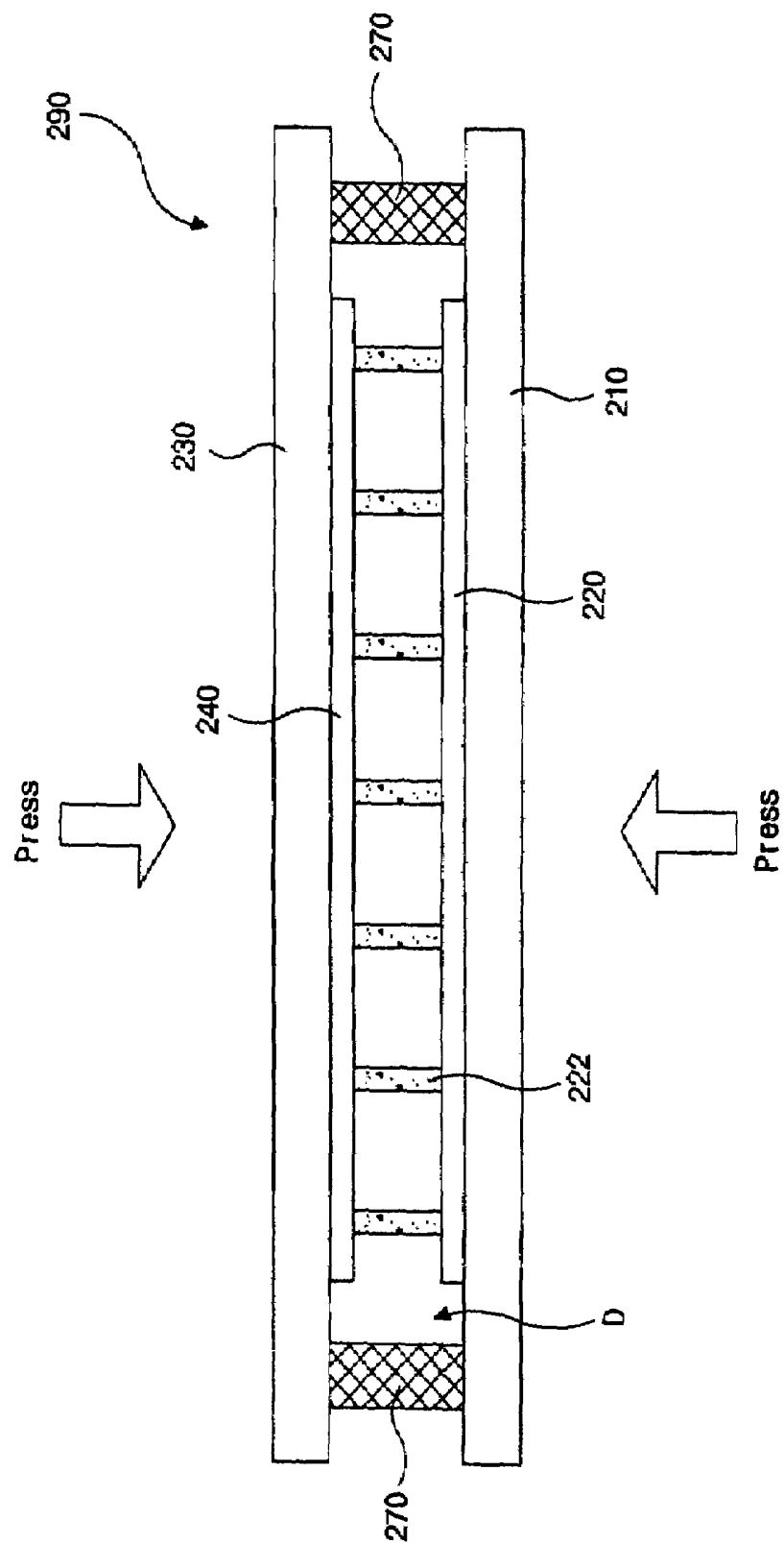
FIG. 7

FIG. 8



ORGANIC ELECTROLUMINESCENT DISPLAY DEVICE AND METHOD OF FABRICATING THE SAME

This is a divisional of application Ser. No. 10/329,485, filed on Dec. 27, 2002, now U.S. Pat. No. 6,922,015, issued Jul. 26, 2005.

The present invention claims the benefit of the Korean Patent Application No. P2002-022813 filed in Korea on Apr. 25, 2002, which is hereby incorporated by reference.

BACKGROUND OF THE INVENTION

1. Field of the Invention

The present invention relates to an electroluminescent display device, and more particularly, to an organic electroluminescent display device and a method of fabricating the same.

2. Discussion of the Related Art

In general, flat panel displays have been commonly used as display devices due to their thin profile, light weight, and low power consumption. Examples of flat panel displays include liquid crystal displays (LCDs), plasma display panels (PDPs), field emission displays (FEDs), and electroluminescent displays (ELDs). The electroluminescent displays may be categorized into inorganic electroluminescent displays (IELD) devices and organic electroluminescent display (OLED) devices depending upon source material for exciting carriers. The organic electroluminescence display (OLED) devices have high brightness, low driving voltage, and produce natural color images from the entire visible light wavelength range. In addition, the OLED devices have wide viewing angles and excellent contrast ratios because of their self-luminescence. Since the OLED devices do not require additional light sources, such as a backlight, the OLED devices have relatively small size, light weight, and low power consumption as compared with the LCD devices. Furthermore, the OLED devices may be driven by low voltage direct current (DC), and have short microsecond response times. Since the OLED devices are solid phase devices, they sufficiently withstand external impacts and have greater operational temperature ranges. In addition, the OLED devices may be manufactured at low cost. For example, only deposition and encapsulation apparatus are necessary for manufacturing the organic EL devices, thereby simplifying manufacturing processes.

The OLED devices may be classified into passive matrix-type and active matrix-type, depending upon a method for driving the devices. The passive matrix-type OLED devices do not have additional thin film transistors (TFTs), and are commonly used. The passive matrix-type OLED devices have scanning lines and signal lines that perpendicularly cross each other in a matrix shape. Since a scanning voltage is sequentially applied to the scanning lines to operate each pixel, an instantaneous brightness of each pixel during a selection period should reach a value resulting from multiplying the average brightness by the number of the scanning lines to obtain a required average brightness. Accordingly, as the number of the scanning lines increases, the applied voltage and current also increase. Thus, the passive matrix-type OLED devices are not adequate for high resolution display and large-sized areas since the devices easily deteriorate during use and power consumption is high.

Since the passive matrix-type OLED devices have many limitations in regards to image resolution, power consumption, and operational lifetime, the active matrix-type OLED devices have developed as next generation display devices

for high resolution and large display area displays. In the active matrix-type OLED device, a thin film transistor (TFT) is disposed at each sub-pixel as a switching element that turns each sub-pixel ON and OFF. A first electrode connected to the TFT is turned ON/OFF by the sub-pixel, and a second electrode facing the first electrode functions as a common electrode. In addition, a voltage applied to the pixel is stored in a storage capacitor, thereby maintaining the voltage and driving the device until a voltage of next frame is applied, regardless of the number of the scanning lines. As a result, since an equivalent brightness is obtained with a low applied current, an active matrix-type OLED device having low power consumption, high resolution, and large area may be made.

FIG. 1 is an equivalent circuit diagram showing a pixel structure of an active matrix organic electroluminescent display device according to the related art. In FIG. 1, a scanning line 1 is arranged along a first direction, and a signal line 2 and a power line 3 that are spaced apart from each other are arranged along a second direction perpendicular to the first direction. The signal line 2 and the power line 3 cross the scanning line 1, thereby defining a pixel region "P." A switching TFT "T_S," i.e., an addressing element, is connected to the scanning line 1 and the signal line 2, and a storage capacitor "C_{ST}" is connected to the switching TFT "T_S" and the power line 3. A driving TFT "T_D," i.e., a current source element, is connected to the storage capacitor "C_{ST}" and the power line 3, and an organic EL diode "D_{EL}" is connected to the driving TFT "T_D." When a forward current is applied to the organic EL diode "D_{EL}," an electron and a hole are recombined to generate an electron-hole pair through the P(positive)-N(negative) junction between an anode that provides the hole and a cathode that provides the electron. The electron-hole pair has an energy that is lower than the separated electron and hole. Accordingly, an energy difference occurs between the recombination and the separated of the electron-hole pair, whereby light is emitted due to the energy difference. The switching TFT "T_S" adjusts the forward current through the driving TFT "T_D" and stores charges in the storage capacitor "C_{ST}."

The OLED devices are commonly categorized as top emission-type and bottom emission-type according to a direction of the emitted light.

FIG. 2 is a cross sectional view of a bottom emission-type organic electro-luminescent display device according to the related art. In FIG. 2, one pixel region is shown to include red, green and blue sub-pixel regions, and first and second substrates 10 and 30 face and are spaced apart from each other. A peripheral portion of the first and second substrates 10 and 30 are sealed with a seal pattern 40. A thin film transistor (TFT) "T" is formed at each sub-pixel region "P_{sub}" on an inner surface of the first substrate 10, and a first electrode 12 is connected to the TFT "T." An organic electroluminescent layer 14 includes luminescent materials of red, green, and blue is formed on the TFT "T." In addition, the first electrode 12 and a second electrode 16 are formed on the organic electroluminescent layer 14, whereby the first and second electrodes 12 and 16 apply an electric field to the organic electroluminescent layer 14. A desiccant (not shown) is formed in an inner surface of the second substrate 30 to shield from external moisture, and the desiccant is attached to the second substrate 30 by an adhesive (not shown), such as semi-transparent tape.

In the bottom emission-type OLED device, for example, the first electrode 12 functions as an anode and is made of a transparent conductive material, and the second electrode 16 functions as a cathode and is made of a metallic material

of low work function. Accordingly, the organic electroluminescent layer **14** is composed of a hole injection layer **14a**, a hole transporting layer **14b**, an emission layer **14c**, and an electron transporting layer **14d** formed over the first electrode **12**. The emission layer **14c** has a structure where emissive materials of red, green, and blue are alternately disposed at each sub-pixel region "P_{sub}".

FIG. 3 is a cross sectional view of a sub-pixel region of a bottom emission-type organic electroluminescent display device according to the related art. In FIG. 3, a TFT "T" having a semiconductor layer **62**, a gate electrode **68**, and source and drain electrodes **80** and **82** is formed on a substrate **10**. The source electrode **80** of the TFT "T" is connected to a storage capacitor "C_{ST}" and the drain electrode **82** is connected to an organic electroluminescent (EL) diode "D_{EL}". The storage capacitor "C_{ST}" includes a power electrode **72** and a capacitor electrode **64** that face each other with an insulating layer interposed between the power electrode **72** and the capacitor electrode **64**, and the capacitor electrode **64** is made of the same material as the semiconductor layer **62**. The TFT "T" and the storage capacitor "C_{ST}" are commonly referred to as array elements "A." The organic EL diode "D_{EL}" includes first and second electrodes **12** and **16** that face each other with an organic EL layer **14** interposed therebetween. The source electrode **80** of the TFT "T" is connected to the power electrode **72** of the storage capacitor "C_{ST}" and the drain electrode **82** of the TFT "T" is connected to the first electrode **12** of the organic EL diode "D_{EL}". In addition, the array elements "A" and the organic EL diode "D_{EL}" are formed on the same substrate.

FIG. 4 is a flow chart of a fabricating process of an organic electroluminescent display device according to the related art. At step ST1, array elements are formed on a first substrate that include a scanning line, a signal line, a power line, a switching TFT, and a driving TFT. The signal line and the power line cross the scanning line and are spaced apart from each other. The switching TFT is disposed at a cross of the scanning line and the signal line, while the driving TFT is disposed at a cross of the scanning line and the power line.

At step ST2, a first electrode of an organic EL diode is formed over the array elements. The first electrode is connected to the driving TFT of each sub-pixel region.

At step ST3, an organic electroluminescent layer of the organic EL diode is formed on the first electrode. If the first electrode is designed to function as an anode, the organic EL layer can be composed of a hole injection layer, a hole transporting layer, an emission layer, and an electron transporting layer.

At step ST4, a second electrode of the EL diode is formed on the organic EL layer. The second electrode is formed over an entire surface of the first substrate to function as a common electrode.

At step ST5, the first substrate is encapsulated with a second substrate. The second substrate protects the first substrate from external impact and prevents damage to the organic EL layer from any ambient air. A desiccant may be included in an inner surface of the second substrate.

The OLED device is fabricated through encapsulating the first substrate including the array elements and the organic EL diode with the second substrate. In addition, a yield of the active matrix OLED device depends on yields of the thin film transistor and the organic layer. Although the thin film transistor may adequately function, the yield of the active matrix OLED device varies due to impurities in the process of forming the organic layer to a thickness of about 1,000 Å. Accordingly, the yield of the active matrix OLED is reduced

because of the impurities, and results in loss of manufacturing costs and source materials.

In addition, the active matrix OLED device is a bottom emission-type device having high stability and variable degrees of freedom during the fabrication process, but has a reduced aperture ratio. Thus, the bottom emission-type active matrix OLED device is problematic in implementation as a high aperture device. On the other hand, a top emission-type active matrix OLED has a high aperture ratio, and is easily fabricated. However, in the top emission-type active matrix OLED device, a choice of a material for the cathode electrode is limited since a cathode electrode is generally disposed over the organic layer. Accordingly, light transmittance is limited, and a luminous efficacy is reduced. Furthermore, in order to improve the transmittance, since a passivation layer should be formed in a thin film, air infiltration is not sufficiently prevented.

SUMMARY OF THE INVENTION

Accordingly, the present invention is directed to an organic electroluminescent display device and a method of fabricating the same that substantially obviates one or more of problems due to limitations and disadvantages of the related art.

An object of the present invention is to provide an organic electroluminescent display device and a method of fabricating the same that has a high aperture ratio.

Another object of the present invention is to provide an organic electroluminescent display device and a method of fabricating the same that provides for improved yield and productivity.

Another object of the present invention is to provide an organic electro-luminescent display device and a method of fabricating the same that are reliable.

Additional features and advantages of the invention will be set forth in the description which follows and in part will be apparent from the description, or may be learned by practice of the invention. The objectives and other advantages of the invention will be realized and attained by the structure particularly pointed out in the written description and claims hereof as well as the appended drawings.

To achieve these and other advantages and in accordance with the purpose of the present invention, as embodied and broadly described, an organic electroluminescent display device includes a first substrate, a second substrate spaced apart from and facing the first substrate to form a space therebetween, an array element on an inner surface of the first substrate, an organic electroluminescent diode on an inner surface of the second substrate, a seal pattern along a peripheral portion between the first and second substrates, and a connection pattern electrically interconnecting the array element and the organic electroluminescent diode, wherein a pressure within the space between the first and second substrates is lower than an ambient atmospheric pressure.

In another aspect, method of fabricating an organic electroluminescent display device includes forming an array element and connection pattern on a first substrate, forming a connection pattern electrically connected to the array element, forming an organic electroluminescent diode on a second substrate, forming a seal pattern along a peripheral portion between the first and second substrates such that the array element and the organic electroluminescent diode face each other, performing a first bonding of the first and second substrates within a vacuum chamber by pressing the seal pattern to electrically interconnect the connection pattern

and the organic electroluminescent diode, the first bonding providing a first space between the first and second substrates having a first pressure less than an ambient atmospheric pressure, performing a first hardening of the seal pattern, performing a second bonding of the first and second substrate in the vacuum chamber at the ambient atmospheric pressure, and performing a second hardening of the seal pattern.

It is to be understood that both the foregoing general description and the following detailed description are exemplary and explanatory and are intended to provide further explanation of the invention as claimed.

BRIEF DESCRIPTION OF THE DRAWINGS

The accompanying drawings, which are included to provide a further understanding of the invention and are incorporated in and constitute a part of this application, illustrate embodiments of the invention and together with the description serve to explain the principle of the invention. In the drawings:

FIG. 1 is an equivalent circuit diagram showing a pixel structure of an active matrix organic electroluminescent display device according to the related art;

FIG. 2 is a cross sectional view of a bottom emission-type organic electro-luminescent display device according to the related art;

FIG. 3 is a cross sectional view of a sub-pixel region of a bottom emission-type organic electroluminescent display device according to the related art;

FIG. 4 is a flow chart of a fabricating process of an organic electroluminescent display device according to the related art;

FIG. 5 is a cross sectional view of an exemplary active matrix organic electro-luminescent display device according to the present invention;

FIG. 6 is a cross sectional view of another exemplary active matrix organic electro-luminescent display device according to the present invention;

FIG. 7 is a flow chart of an exemplary attachment process of an organic electro-luminescent display device according to the present invention; and

FIG. 8 is a cross sectional view of an exemplary attachment apparatus of an organic electroluminescent display device according to the present invention.

DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS

Reference will now be made in detail to the illustrated embodiment of the present invention, an example of which is illustrated in the accompanying drawings.

FIG. 5 is a cross sectional view of an exemplary active matrix organic electroluminescent display device according to the present invention. In FIG. 5, a first substrate 110 and a second substrate 130 may be spaced apart and face each other, and a seal pattern 140 may be formed along a peripheral portion between the first and second substrates 110 and 130. Array elements 120 may be formed on an inner surface of the first substrate 110, and organic electroluminescent (EL) diodes "D_{EL}" may be formed on an inner surface of the second substrate 130. The organic EL diode "D_{EL}" may include a first electrode 132, an organic EL layer 136, and a second electrode 138, wherein the first electrode 132 may be formed on the inner surface of the second substrate 130 to function as a common electrode. A partition wall 134 may be formed on the first electrode 132, and may

be disposed along a border portion between adjacent sub-pixels "P_{sub}" as a separator of the second electrode 138. The organic EL layer 136 may be formed on the first electrode 132 between the adjacent partition walls 134, and the second electrode 138 may be formed on the organic EL layer 136 at each sub-pixel region "P_{sub}".

The organic EL layer 136 may include a first organic material layer 136a, an emission layer 136b, and a second organic material layer 136c. The first organic material layer 136a may be formed on the first electrode 132, and the emission layer 136b may be formed on the first organic material layer 136a to include one of red, green, and blue disposed at each sub-pixel region "P_{sub}". The second organic material layer 136c may be formed on the emission layer 136b, wherein an EL material of the first and second organic material layers 136a and 136c may be determined according to a disposition of anode and cathode electrodes. When the first and second electrodes 132 and 138 are designed as the cathode and anode electrodes, respectively, for example, the first organic material layer 136a may include an electron injection layer and an electron transporting layer, and the second organic material layer 136c may include a hole injection layer and a hole transporting layer.

The array elements 120 may include a thin film transistor (TFT) "T" that may be formed on the first substrate 110 by the sub-pixel region "P_{sub}". A connection pattern 114 may also be formed by the sub-pixel "P_{sub}" over the first substrate 110 including the TFT "T," wherein the connection pattern 114 connects the second electrode 138 to the TFT "T" in order to supply currents to the organic EL diode "D_{EL}". While electrically connecting the organic EL diode "D_{EL}" to the TFT "T," the connection pattern 114 may maintain a uniform gap between the first and second substrates 110 and 130. The connection pattern 114 may include a columnar shape, and may be connected to a drain electrode 112 of the TFT "T" through a drain contact hole 122 formed in a passivation layer 124 to cover the TFT "T." The connection pattern 114 may be connected to a source electrode of the TFT "T" or to an additional metal pattern connected to the TFT "T." The TFT "T" may be a driving TFT connected to the organic EL diode "D_{EL}". The connection pattern 114 may include a conductive material, such as a ductile metallic material having a low resistivity, and may be formed during a process of forming the array elements 120 on the first substrate 110.

The organic EL device shown in FIG. 5 may be a top emission-type device where light is emitted through the second substrate 130. Accordingly, the first electrode 132 may include a transparent conductive material or a half transparent conductive material, and the second electrode 138 may include an opaque conductive material. Preferably, a space "B" between the array elements 120 and the second electrode 138 may be filled with an inert gas, such as nitrogen gas (N₂).

Although not shown, the array elements 120 may also include a scanning line, a signal line, a power line, a switching TFT, and a storage capacitor. The signal line and the power line may be spaced apart from each other to cross the scanning line, and the switching TFT may be disposed at a crossing of the scanning line and the signal line. Thus, a first substrate having array elements and a second substrate having an organic EL diode may be individually provided. In addition, the OLED device may be a top emission-type device where light is emitted through the second substrate. Accordingly, a structure of high aperture ratio and high resolution can be obtained where the production yield is improved. Since the OLED device efficiently blocks the

ambient air, the OLED device is reliable. Moreover, degrees of freedom for arranging the TFT may be increased, and selection of the material for the first electrode may be varied. Furthermore, TFTs having other structures may be used except for a top gate structure, as shown in FIG. 5.

FIG. 6 is a cross sectional view of another exemplary active matrix organic electroluminescent display device according to the present invention. In FIG. 6, a first substrate 150 and a second substrate 160 may be spaced apart and face each other. A seal pattern 182 may be formed along a peripheral portion between the first and second substrates 150 and 160 to attach the first and second substrates 150 and 160 to each other. The seal pattern 182 may have a closed pattern without any openings. Array elements 170 may be formed on an inner surface of the first substrate 150 and organic electro-luminescent (EL) diodes 172 may be formed on an inner surface of the second substrate 160. The organic EL diodes 172 may be connected to the array elements 170 through connection patterns 180 that are formed between the array elements 170 and the organic EL diodes 172.

When attaching the first and second substrates 150 and 160, a portion corresponding to the seal pattern 182 may be mechanically pressed. Accordingly, first regions between the first and second substrates 150 and 160 far away from the seal pattern 182 may have a lower internal pressure than second regions adjacent to the seal pattern 182. Thus, the first regions between the first and second substrates 150 and 160 far away from the seal pattern 182 may have a larger volume than the second regions adjacent to the seal pattern 182. Accordingly, bonding of the first and second substrates 150 and 160 may be poor due to a lack of compression of the connection patterns within a space "C," whereby the organic EL diode 172 and the connection pattern 180 may be disconnected from each other. Accordingly, currents may not be adequately supplied to the organic EL diode 172 due to the poor connections, and image display quality may be poor since light is not emitted in the corresponding sub-pixel regions. This is commonly referred to as a pixel defect.

On the other hand, wherein the connection patterns 180 are weakly connected to the organic EL diode 172, the OLED device may be partially degraded due to localized generation of heat by the currents. Accordingly, spots may occur if the OLED is driven for long periods time.

FIG. 7 is a flow chart of an exemplary attachment process of an organic electroluminescent display device according to the present invention. At step ST11, in a vacuum condition, a first substrate that includes array elements and connection patterns and a second substrate that includes organic EL diodes may be initially attached. A seal pattern may be formed along a peripheral portion between the first and second substrates, and the first and second substrates may be attached together by mechanical pressing the seal pattern. The vacuum condition may be maintained by using a vacuum chamber having a gas injecting portion and an exhaust port. For example, the pressure within the vacuum chamber may be within a range of about 0.3 torr to about 0.7 torr, and may be controlled by an amount of gas flowing into the chamber.

At step ST12, the seal pattern between the initially attached substrates may be initially hardened. Accordingly, during subsequent processing steps, the seal pattern may be prevented from flowing into a space between the first and second substrates.

At step ST13, the initially attached first and second substrates may be finally attached. For example, the gas within the vacuum chamber may be exhausted, and an internal pressure of the vacuum chamber may be increased to atmospheric pressure. Thus, a space between the initially bonded first and second substrates may have a pressure lower than the atmospheric pressure inside of the vacuum

chamber. Accordingly, the lower pressure within the space between the first and second substrates may function as a bonding force. In addition, since the pressure of the space between the bonded first and second substrates may be lower than the atmospheric pressure inside the vacuum chamber, a uniform pressure provided across an entire surface of the bonded first and second substrates. Accordingly, bending of the substrates may be prevented, thereby improving contact of the organic EL diodes and the connection patterns.

At step ST14, after the first and second substrates are finally attached, the seal pattern may be additionally hardened.

At step ST15, after the seal pattern is additionally hardened, fabrication of the OLED device may be complete. However, additional process steps may be added to further fabricate the OLED device.

FIG. 8 is a cross sectional view of an exemplary attachment apparatus of an organic electroluminescent display device according to the present invention. In FIG. 8, array elements 220 and connection patterns 222 may be formed on an inner surface of a first substrate 210, and organic EL diodes 240 may be formed on an inner surface of a second substrate 230. The organic EL diodes 240 may be electrically connected to the array elements 220 through the connection patterns 222. A seal pattern 270 may be formed along a peripheral portion between the first and second substrates 210 and 230 to surround the array elements 220, the connection patterns 222, and the organic EL diodes 240. In addition, an interior space "D" between the first and second substrates 210 and 230 may have a lower pressure than an exterior of the OLED device 290. Thus, pressure is applied across an entire surface of the substrates 210 and 230 during a bonding process, whereby bonding of the organic EL diodes 240 and the connection patterns 222 is improved. Although not shown, the array elements 220 may include a TFT positioned by sub-pixel regions, and the organic EL diodes may include an organic electroluminescent layer and an electrode patterned by the sub-pixel regions.

It will be apparent to those skilled in the art that various modifications and variations can be made in the organic electroluminescent display device and the method of fabricating the same of the present invention without departing from the spirit or scope of the inventions. Thus, it is intended that the present invention covers the modifications and variations of this invention provided they come within the scope of the appended claims and their equivalents.

What is claimed is:

1. A method of fabricating an organic electroluminescent display device, comprising steps of:

forming an array element and connection pattern on a first substrate;

forming a connection pattern electrically connected to the array element;

forming an organic electroluminescent diode on a second substrate;

forming a seal pattern along a peripheral portion between the first and second substrates such that the array element and the organic electroluminescent diode face each other;

performing a first bonding of the first and second substrates within a vacuum chamber by pressing the seal pattern to electrically interconnect the connection pattern and the organic electroluminescent diode, the first bonding providing a first space between the first and second substrates having a first pressure less than an atmospheric pressure; and

performing a first hardening of the seal pattern; and

performing a second bonding of the first and second substrate in the vacuum chamber at the atmospheric pressure.

9

2. The method according to claim 1, wherein the pressure within the chamber is controlled with gas.

3. The method according to claim 1, wherein the first pressure is within a range of about 0.3 torr to about 0.7 torr.

4. The method according to claim 1, wherein the organic electroluminescent diode includes a first electrode, an organic electroluminescent layer, and a second electrode adjacent to a sub-pixel region.

5. The method according to claim 4, wherein the second electrode is electrically interconnected to the connection pattern.

6. The method according to claim 5, wherein the first electrode functions as an anode, and the second electrode functions as a cathode.

7. The method according to claim 6, wherein the organic electroluminescent layer includes a hole injection layer, a hole transporting layer, an emission layer, an electron transporting layer, and an electron injection layer.

8. The method according to claim 1, further comprising performing a second hardening of the seal pattern after the second bonding.

9. A method of fabricating an organic electroluminescent device, comprising steps of:

10

forming an array element on a first substrate having a pixel region;

forming an organic electroluminescent diode on a second substrate;

forming a connection pattern to electrically interconnect the first substrate and the second substrate;

connecting the first substrate and the second substrate electrically with the connection pattern;

forming a seal pattern along a peripheral portion between the first and second substrates such that the array element of the organic electroluminescent diode face each other;

performing a first bonding of the first and second substrates within a vacuum chamber by pressing the seal pattern;

performing a first hardening of the seal pattern;

performing a second bonding of the first and second substrates within the vacuum chamber at atmospheric pressure; and

performing a second hardening of the seal pattern.

* * * * *

专利名称(译)	有机电致发光显示装置及其制造方法		
公开(公告)号	US7021984	公开(公告)日	2006-04-04
申请号	US10/885119	申请日	2004-07-07
[标]申请(专利权)人(译)	乐金显示有限公司		
申请(专利权)人(译)	LG.飞利浦液晶CO. , LTD.		
当前申请(专利权)人(译)	LG DISPLAY CO. , LTD.		
[标]发明人	PARK JAE YONG KIM OCK HEE YOO CHOONG KEUN LEE NAM YANG KIM KWAN SOO		
发明人	PARK, JAE-YONG KIM, OCK-HEE YOO, CHOONG-KEUN LEE, NAM-YANG KIM, KWAN-SOO		
IPC分类号	H05B33/10 H01J9/26 G02F1/13 G09G3/30 H01L27/32 H01L51/50 H01L51/52 H05B33/12 H05B33/26		
CPC分类号	H01L27/3253 H01L51/5237 H01L27/3251 H01L27/3211 H01L27/3246 H01L2251/5315 H01L51/524 H01L51/5243 H01L51/525		
代理机构(译)	摩根路易斯律师事务所		
优先权	1020020022813 2002-04-25 KR		
其他公开文献	US20040242117A1		
外部链接	Espacenet USPTO		

摘要(译)

有机电致发光显示装置包括：第一基板；第二基板，与第一基板隔开并面对第一基板以在它们之间形成空间；阵列元件，在第一基板的内表面上；有机电致发光二极管，在第二基板的内表面上；衬底，沿着第一和第二衬底之间的外围部分的密封图案以及将阵列元件和有机电致发光二极管电互连的连接图案，其中第一和第二衬底之间的空间内的压力低于环境大气压。

